Attorney Docket No. 0553-0166.01

HE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re Application of:

Shunpei YAMAZAKI et al

Serial No.: 10/629,069

Filed: July 29, 2003

Art Unit: 2826

Examiner: Fetsum Abraham

For: WIRING MATERIAL AND A SEMICONDUCTOR)

DEVICE HAVING A WIRING USING THE

MATERIAL, AND THE MANUFACTURING METHOD THEREOF

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to:

Commissioner for Patents, P.O. Box 1450,

Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on 6/14/09

Shannow Wallace

Date: June 14 2006

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

Pursuant to 37 C.F.R. §1.97, Applicant hereby calls the Examiner's attention to documents listed on the attached form, which documents may be material to the examination of this application. Copies of the references are enclosed herewith for the Examiner's consideration.

REFERENCES CITED HEREIN

The references cited herein were first disclosed by

Applicants in an IDS filed on July 29, 2003. Each of these
references was either previously submitted or was cited by the

Patent Office in parent application 09/527,437, which is relied

upon for an earlier filing date under 35 USC 120. Therefore, under 37 CFR \$1.98(d), it is not necessary to file these references. However, to ensure that these references are considered, Applicants are now submitting a copy of each foreign reference and publication for the Examiner's entry and consideration.

No inference should be drawn that the attached list sets forth a comprehensive investigation of the prior art, that any or all are pertinent to the invention, or that any apparatus disclosed is equivalent to the subject invention.

The citation of the above-discussed documents is not to be construed as an assertion that more pertinent art could not possibly be in existence. Citation of any document herein is not to be construed as an admission that any subject matter disclosed in the document is necessarily within the inventive field of endeavor, that any disclosure is necessarily prior in time to a particular date which may be relevant to the instant patent application, and/or that any disclosure is otherwise necessarily prior art with respect to the instant invention.

Applicant also respectfully reserves the right to later set forth how the instant invention is distinguished over the disclosure of any document or other art, including the disclosure of those documents discussed herein, that may be cited by the Examiner in rejecting a claim in the instant patent application.

FEE

Applicants do not believe a fee is due for this IDS as this IDS and references were already properly submitted and cited. However, if any fee is required for this IDS, please charge our Deposit Account No. 50/1039.

Respectfully submitted,

Mark J. Murphy

Registration No.: 34,225

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JUN 1 6 2006 TO BLICATIONS CITED BY APPLICANT			Atty. Docket No. 0553-0166.01	<u>Serial No.</u> 10/629,069		
			<u>Applicant</u> Shunpei YAMAZAKI et al			
			<u>Filing Date</u> July 29, 2003	<u>Group</u> 2826		
US PATENT DOCUMENTS						
*EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB- CLASS	FILING DATE
FOREIGN PATENT DOCUMENTS						
	DOCUMENT NUMBER	DATE	NAME	English Abstract	English Trans.	FILING DATE
	JP 05-093267 JP 05-263226 JP 07-076771 JP 07-130652 JP 08-153722 WO 95/16797 EP 0 735 152 A1 JP 10-247735 JP 11-133463 EP 0 947 593 A2	04/16/93 10/12/93 03/20/95 05/19/95 06/11/96 06/22/96 10/02/96 09/14/98 05/21/99 10/06/99	Japan Energy Corp. Semiconductor Energy Lab Co. Ltd. Toshiba Corp. Toshiba KK Kabushiki Kaisha Toshiba Semiconductor Energy Lab Co. Ltd. Semiconductor Energy Lab Co. Ltd. Kabushiki Kaisha Toshiba	X X X X X		10/01/91 03/17/92 09/08/93 10/29/93 09/29/95 12/14/94 12/14/94 03/03/97 10/31/97 12/14/94
	JP 2001- 056485	02/27/01	Semiconductor Energy Lab Co. Ltd.	X		07/22/99

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ØTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS

(Include name SADENANO (in CAPITAL LETTERS), title of article or item (book, magazine, journal, serial, symposium, catalog, etc.) date, pages(s), volume-issue number(s), publisher, city and/or country where published).

- 1) YOSHIDA, T. et al, "A Full Color Thresholdless Antiferroelectric LCD Exhibiting Wide Viewing Angle with Fast Response Time, "SID 97 Digest, pp. 841-844, (1997).
- 2) FURUE, H. et al, "Characteristics and Driving Scheme of Polymer-Stabilized Monostable FLCD Exhibiting Fast Response Time and High Contrast Ratio with Gray-Scale Capability, "SID 98 Digest, pp. 782-785, (1998).

EXAMINER:

DATE CONSIDERED:

*EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP form. Draw line through citation if not in conformance and not considered. Include a copy of this form with the next communication to applicant.